

## R-C Thermal Model Parameters

### DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

*Note:*

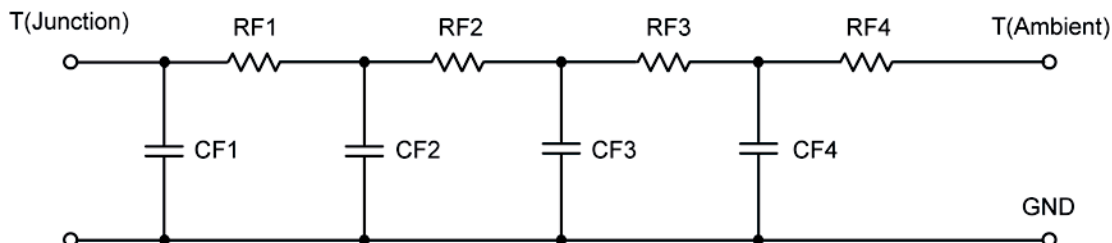
*For a detailed explanation of implementing these values in P-SPICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPICE Platform](#).*

### R-C THERMAL MODEL FOR TANK CONFIGURATION



<b>R-C VALUES FOR TANK CONFIGURATION</b>			
Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RT1	6.2896	N/A	3.1551
RT2	27.4860	N/A	5.4509
RT3	28.1401	N/A	11.8343
RT4	28.0843	N/A	7.5597
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	3.2599 m	N/A	574.8487 u
CT2	34.8260 m	N/A	19.1433 m
CT3	1.6071	N/A	84.4742 m
CT4	2.9566	N/A	11.1212 m

*This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.*

**R-C THERMAL MODEL FOR FILTER CONFIGURATION****R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RF1	7.0889	N/A	3.2893
RF2	28.4864	N/A	10.8428
RF3	27.1549	N/A	6.9755
RF4	27.2698	N/A	6.8924
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	2.2842 m	N/A	516.9421 u
CF2	32.7491 m	N/A	4.8155 m
CF3	893.9001 m	N/A	20.3223 m
CF4	832.5602 m	N/A	125.1171 m

Note: NA indicates not applicable

## Reference:

[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya, IEEE / SEMITHERM 2002

